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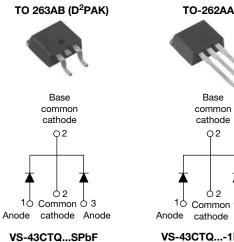
RoHS

COMPLIANT

HALOGEN

FREE

High Performance Schottky Rectifier, 2 x 20 A



Base common cathode 02 02 Common 👌 3 cathode Anode

VS-43CTQ...-1PbF

PRODUCT SUMMARY					
Package	TO-263AB (D ² PAK), TO-262AA				
I _{F(AV)}	2 x 20 A				
V _R	80 V, 100 V				
V _F at I _F	0.67 V				
I _{RM} max.	11 mA at 125 °C				
T _J max.	175 °C				
Diode variation	Common cathode				
E _{AS}	7.50 mJ				

FEATURES

- 175 °C T_J operation
- · Center tap configuration
- · Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	40	A		
V _{RRM}		80/100	V		
I _{FSM}	t _p = 5 μs sine	850	А		
V _F	20 A_{pk} , T_J = 125 °C (per leg)	0.67	V		
TJ	Range	-55 to +175	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-43CTQ080SPbF VS-43CTQ080-1PbF	VS-43CTQ100SPbF VS-43CTQ100-1PbF	UNITS
Maximum DC reverse voltage	V _R	80	100	V
Maximum working peak reverse voltage	V _{RWM}	80	100	v

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST COND	ITIONS	VALUES	UNITS
Maximum average	per leg				20	
forward current See fig. 5	per device	device $I_{F(AV)}$ 50 % duty cycle at T _C = 135 °C, rectangular wa		C, rectangular waveform	40	A
Maximum peak one cycle non-r	ycle non-repetitive		5 µs sine or 3 µs rect. pulse	Following any rated load	850	A
surge current per leg See fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	275	
Non-repetitive avalanche energy	y per leg	E _{AS}	$T_J = 25 \ ^{\circ}C, \ I_{AS} = 0.50 \ A, \ L = 60$	mH	7.50	mJ
Repetitive avalanche current pe	r leg	I _{AR}	Current decaying linearly to zer Frequency limited by T_J maxim	•	0.50	А

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ELECTRICAL SPECIFICATION	S				
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		20 A	T.I = 25 °C	0.81	V
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	40 A	1j=23 C	0.98	
See fig. 1	VFM (')	20 A	T.I = 125 °C	0.67	
		40 A	1j = 125 C	0.81	
Maximum reverse leakage current per leg	I _{BM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	1	1 mA
See fig. 2	IRM \''	T _J = 125 °C		11	
Threshold voltage	V _{F(TO)}			0.71	V
Forward slope resistance	r _t	$T_J = T_J$ maximum		0.43	mΩ
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range	ge 100 kHz to 1 MHz), 25 °C	1480	pF
Typical series inductance per leg	L _S	Measured lead to lead 5 m	nm from package body	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

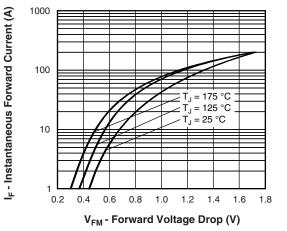
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

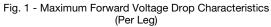
THERMAL - MECHAN	ICAL SP	ECIFICAT	IONS			
PARAMETER SYMBOL TEST CONDITIONS VALUES UNIT						
Maximum junction and storage temperature range	e	T _J , T _{Stg}		-55 to +175	°C	
Maximum thermal resistance, junction to case per leg		D		2.0		
Maximum thermal resistance, junction to case per package		R _{thJC}	DC operation	1.0	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	-	
Approvimeto weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum			6 (5)	kgf ⋅ cm	
Mounting torque	maximum			12 (10)	(lbf · in)	
				43CT0	2080S	
Madine device			Case style TO-263AB (D ² PAK)	43CT0	Q100S	
Marking device	Marking device			43CTC	080-1	
			Case style TO-262AA	43CTC	43CTQ100-1	

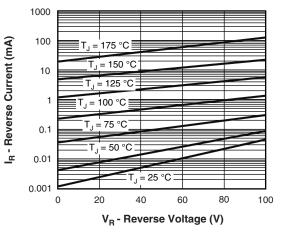


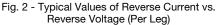
VS-43CTQ...SPbF, VS-43CTQ...-1PbF Series

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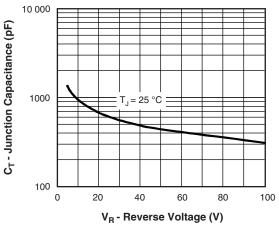


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

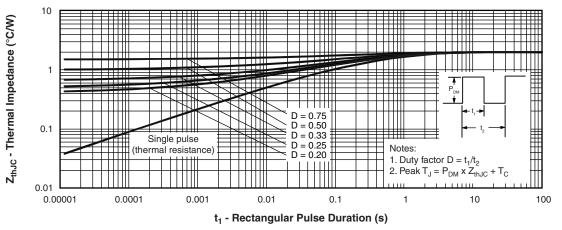


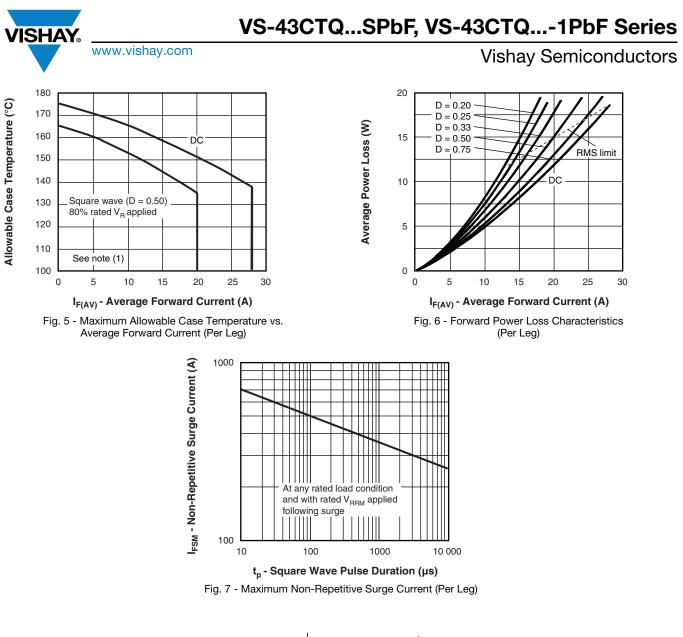
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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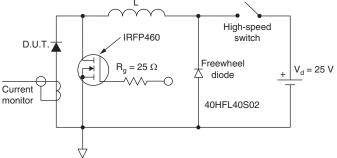


Fig. 8 - Unclamped Inductive Test Circuit

Note

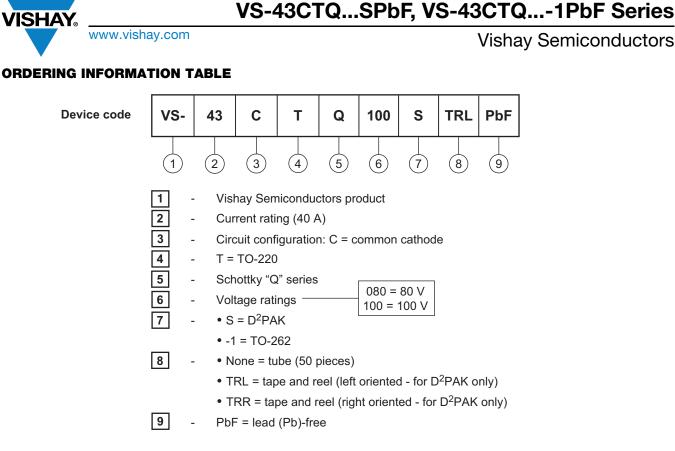
- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
- Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 D)$; $I_R \text{ at } V_{R1} = 10 \text{ V}$

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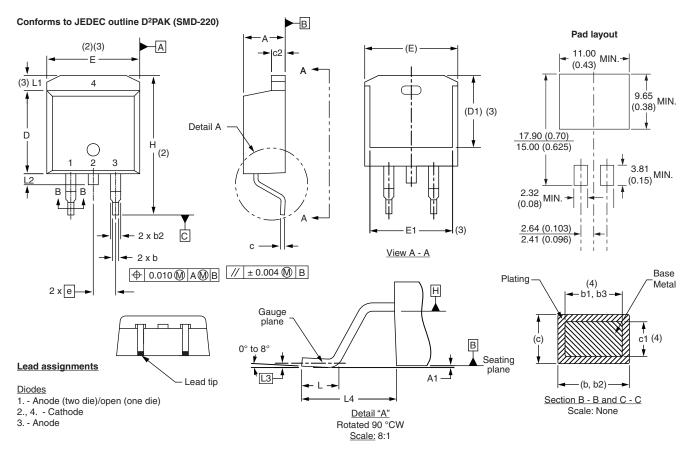
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LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95014			
Part marking information	www.vishay.com/doc?95008			
Packaging information	www.vishay.com/doc?95032			
SPICE model	www.vishay.com/doc?95065			

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D²PAK, TO-262



DIMENSIONS - D²PAK in millimeters and inches

SHA

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
с	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

INCHES

MILLIMETERS

⁽⁷⁾ Outline conforms to JEDEC outline TO-263AB

Notes

 $^{(1)}\,$ Dimensioning and tolerancing per ASME Y14.5 M-1994 $\,$

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- ⁽⁴⁾ Dimension b1 and c1 apply to base metal only
- ⁽⁵⁾ Datum A and B to be determined at datum plane H
- ⁽⁶⁾ Controlling dimension: inch

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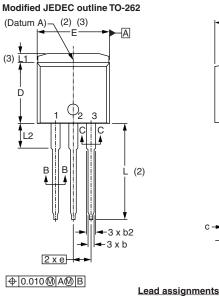
Outline Dimensions

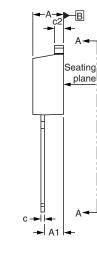
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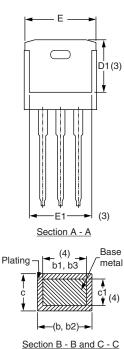
D²PAK, TO-262



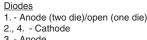
DIMENSIONS - TO-262 in millimeters and inches

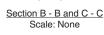






Lead tip





SYMBOL	MILLIMETERS		INCI	NOTES	
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	8.51 9.65		0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

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actual package outline

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the

3. - Anode



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